



60-V, N-Channel NexFET™ Power MOSFETs

Check for Samples: [CSD18532KCS](#)

FEATURES

- Ultra Low Qg and Qgd
- Low Thermal Resistance
- Avalanche Rated
- Logic Level
- Pb Free Terminal Plating
- RoHS Compliant
- Halogen Free
- TO-220 Plastic Package

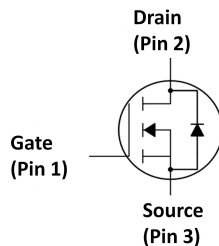
APPLICATIONS

- DC-DC Conversion
- Secondary Side Synchronous Rectifier
- Motor Control

DESCRIPTION

The NexFET™ power MOSFET has been designed to minimize losses in power conversion applications.

Figure 1. Top View



PRODUCT SUMMARY

T _A = 25°C		TYPICAL VALUE	UNIT
V _{DS}	Drain to Source Voltage	60	V
Q _g	Gate Charge Total (10V)	44	nC
Q _{gd}	Gate Charge Gate to Drain	6.9	nC
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 4.5V	4.2 mΩ
		V _{GS} = 10V	3.3 mΩ
V _{GS(th)}	Threshold Voltage	1.8	V

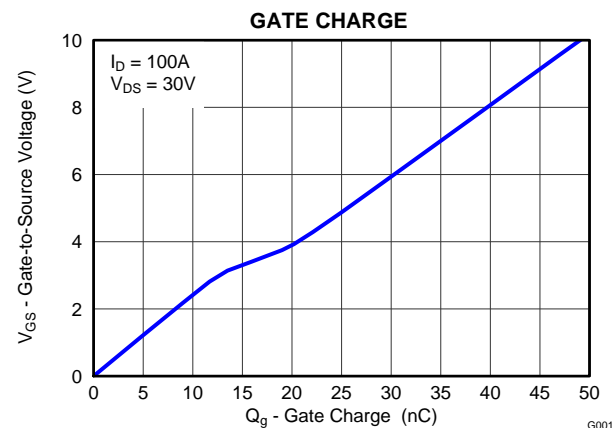
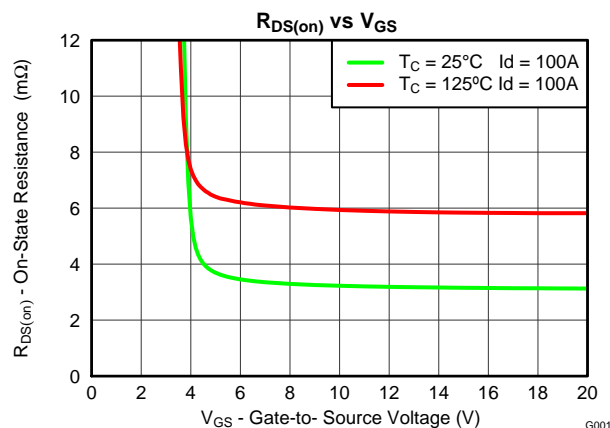
ORDERING INFORMATION

Device	Package	Media	Qty	Ship
CSD18532KCS	TO-220 Plastic Package	Tube	50	Tube

ABSOLUTE MAXIMUM RATINGS

T _A = 25°C		VALUE	UNIT
V _{DS}	Drain to Source Voltage	60	V
V _{GS}	Gate to Source Voltage	±20	V
I _D	Continuous Drain Current (Package limited), T _C = 25°C	100	A
	Continuous Drain Current (Silicon limited), T _C = 25°C	169	
	Continuous Drain Current (Silicon limited), T _C = 100°C	107	
I _{DM}	Pulsed Drain Current ⁽¹⁾	179	A
P _D	Power Dissipation	216	W
T _J , T _{STG}	Operating Junction and Storage Temperature Range	–55 to 150	°C
E _{AS}	Avalanche Energy, single pulse I _D = 75A, L = 0.1mH, R _G = 25Ω	281	mJ

(1) Pulse duration ≤300μs, duty cycle ≤2%



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ELECTRICAL CHARACTERISTICS

($T_A = 25^\circ\text{C}$ unless otherwise stated)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static Characteristics						
BV _{DSS}	Drain to Source Voltage	V _{GS} = 0V, I _D = 250μA	60			V
I _{DSS}	Drain to Source Leakage Current	V _{GS} = 0V, V _{DS} = 48V			1	μA
I _{GSS}	Gate to Source Leakage Current	V _{DS} = 0V, V _{GS} = 20V			100	nA
V _{GS(th)}	Gate to Source Threshold Voltage	V _{DS} = V _{GS} , I _D = 250μA	1.5	1.8	2.2	V
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 4.5V, I _D = 100A		4.2	5.3	mΩ
		V _{GS} = 10V, I _D = 100A		3.3	4.2	mΩ
g _{fs}	Transconductance	V _{DS} = 30V, I _D = 100A		187		S
Dynamic Characteristics						
C _{iss}	Input Capacitance	V _{GS} = 0V, V _{DS} = 30V, f = 1MHz		3900	4680	pF
C _{oss}	Output Capacitance			470	564	pF
C _{rss}	Reverse Transfer Capacitance			11	14	pF
R _G	Series Gate Resistance			1.3	2.6	Ω
Q _g	Gate Charge Total (4.5V)	V _{DS} = 30V, I _D = 100A		21	25	nC
Q _g	Gate Charge Total (10V)			44	53	nC
Q _{gd}	Gate Charge Gate to Drain			6.9		nC
Q _{gs}	Gate Charge Gate to Source			10		nC
Q _{g(th)}	Gate Charge at V _{th}			7.3		nC
Q _{oss}	Output Charge	V _{DS} = 30V, V _{GS} = 0V		52		nC
t _{d(on)}	Turn On Delay Time	V _{DS} = 30V, V _{GS} = 10V, I _{DS} = 100A, R _G = 0Ω		7.8		ns
t _r	Rise Time			5.3		ns
t _{d(off)}	Turn Off Delay Time			24.2		ns
t _f	Fall Time			5.6		ns
Diode Characteristics						
V _{SD}	Diode Forward Voltage	I _{SD} = 100A, V _{GS} = 0V		0.8	1	V
Q _{rr}	Reverse Recovery Charge	V _{DS} = 30V, I _F = 100A, di/dt = 300A/μs		127		nC
t _{rr}	Reverse Recovery Time			57		ns

THERMAL CHARACTERISTICS

($T_A = 25^\circ\text{C}$ unless otherwise stated)

PARAMETER		MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Thermal Resistance Junction to Case			0.6	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance Junction to Ambient			62	$^\circ\text{C/W}$

TYPICAL MOSFET CHARACTERISTICS

($T_A = 25^\circ\text{C}$ unless otherwise stated)

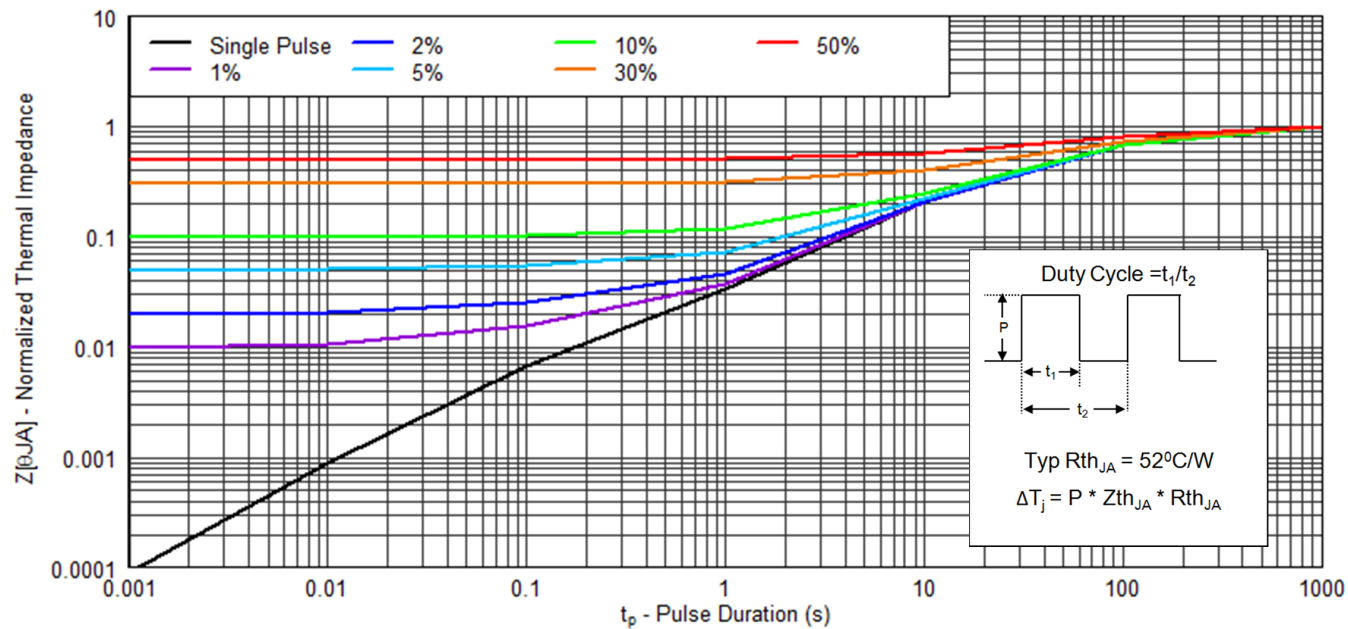


Figure 2. Transient Thermal Impedance

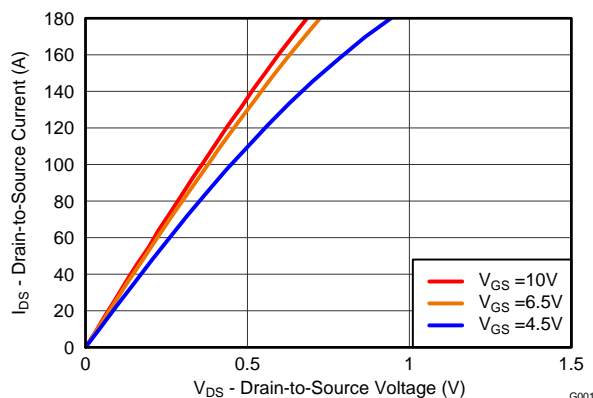


Figure 3. Saturation Characteristics

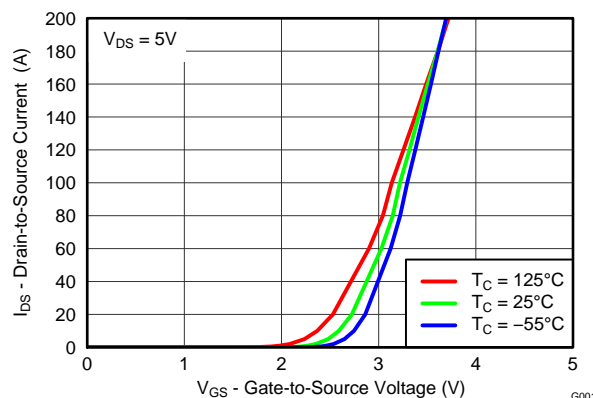


Figure 4. Transfer Characteristics

TYPICAL MOSFET CHARACTERISTICS (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)

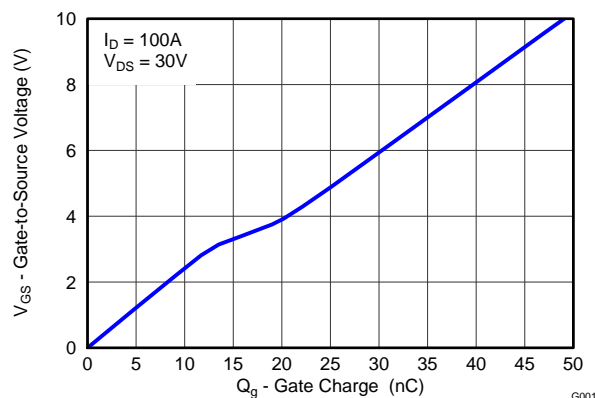


Figure 5. Gate Charge

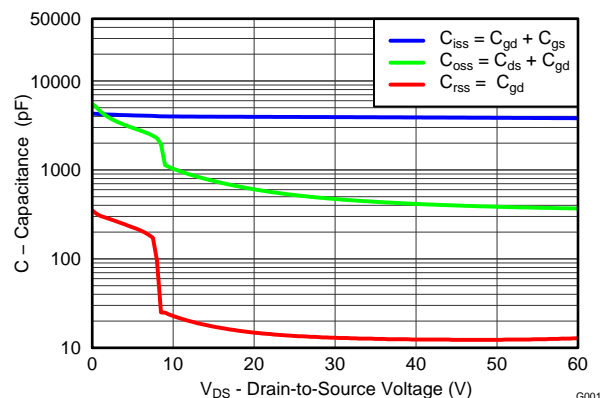


Figure 6. Capacitance

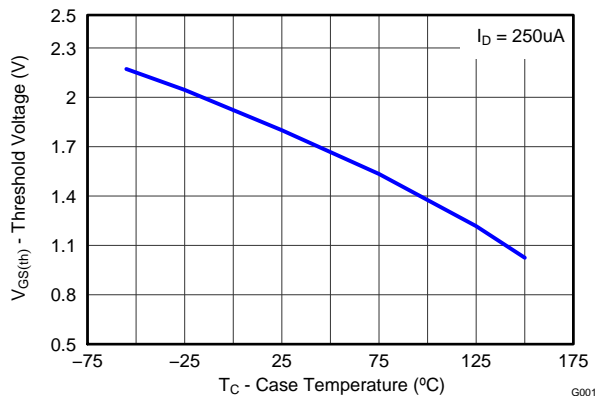


Figure 7. Threshold Voltage vs. Temperature

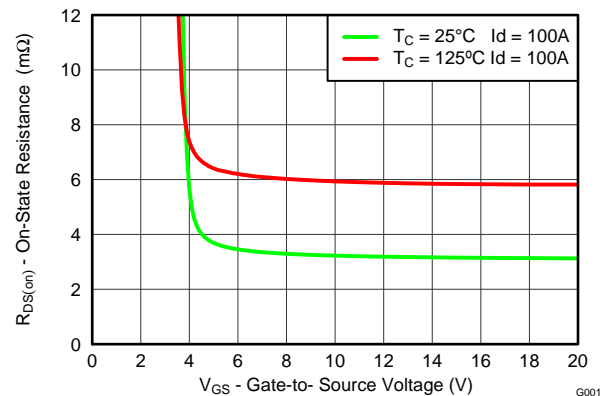


Figure 8. On-State Resistance vs. Gate-to-Source Voltage

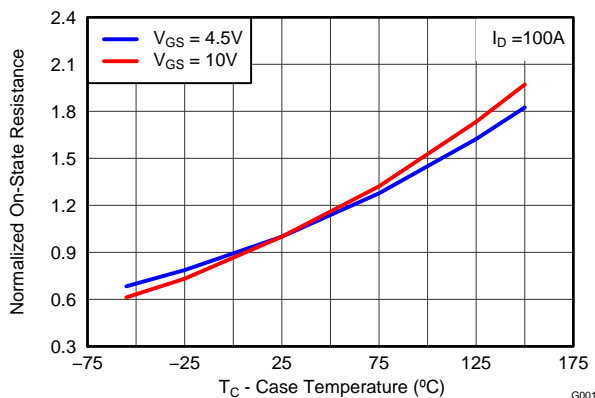


Figure 9. Normalized On-State Resistance vs. Temperature

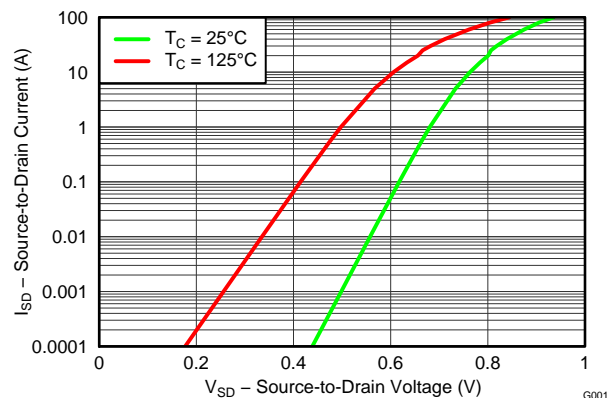


Figure 10. Typical Diode Forward Voltage

TYPICAL MOSFET CHARACTERISTICS (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)

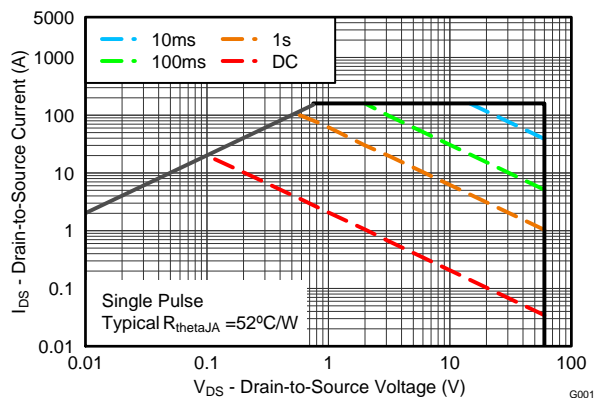


Figure 11. Maximum Safe Operating Area

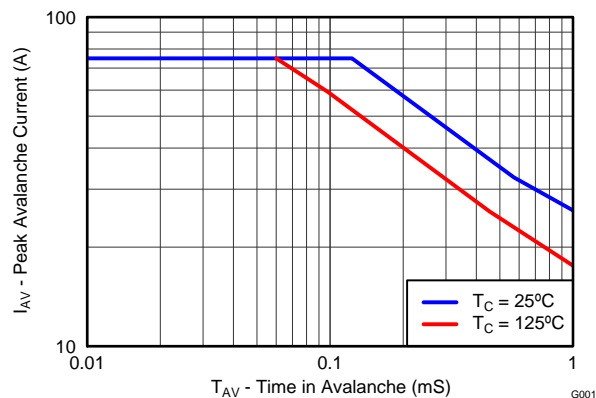


Figure 12. Single Pulse Unclamped Inductive Switching

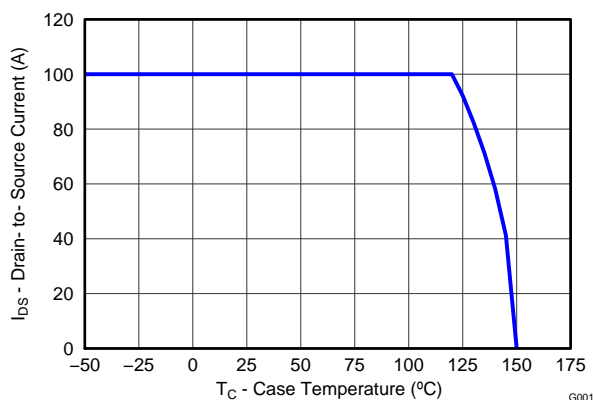
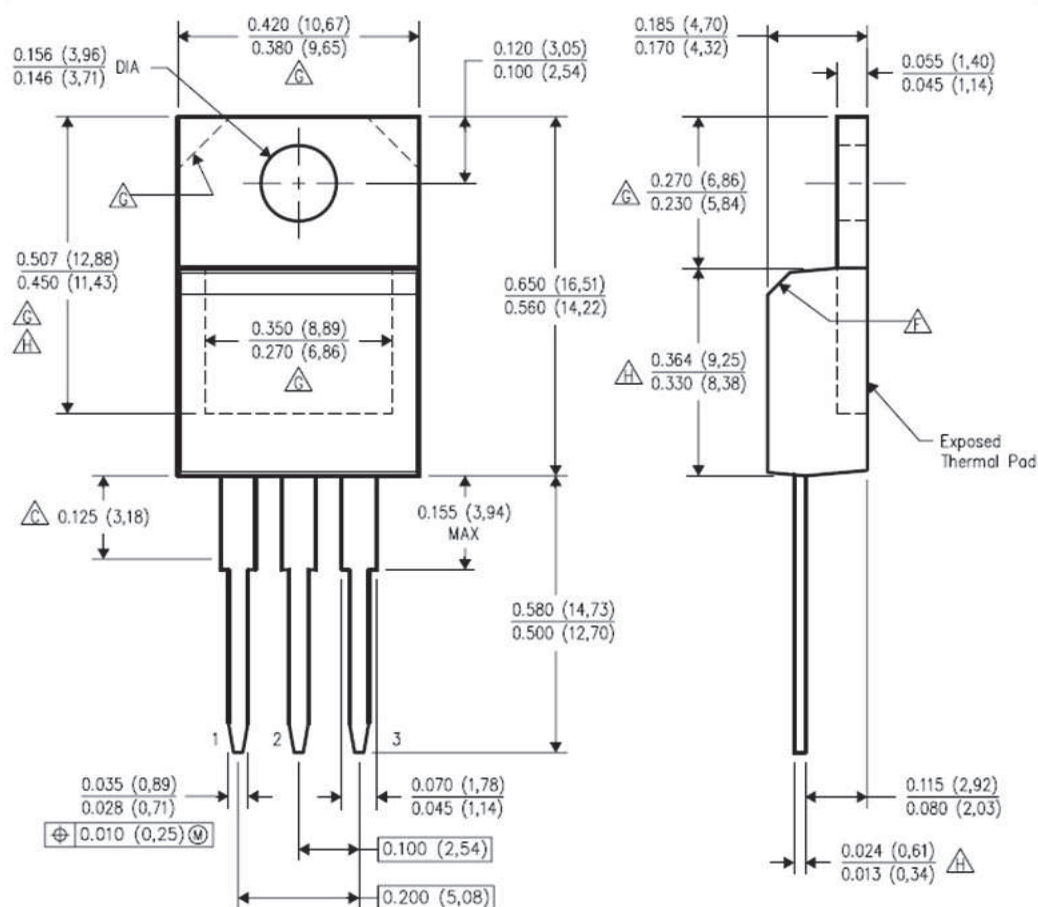


Figure 13. Maximum Drain Current vs. Temperature

MECHANICAL DATA

KCS Package Dimensions



Notes:

1. All linear dimensions are in inches
2. This drawing is subject to change without notice
3. Lead Dimensions are not controlled within "C" area
4. All lead dimensions apply before solder dip
5. The center lead is in electrical contact with the mounting tab
6. The chamfer at "F" is optional
7. Thermal pad contour at "G" optional with these dimensions
8. "H" Falls within JEDEC TO-220 variation AB, except minimum lead thickness, minimum exposed pad length, and maximum body length.

Table 1. Pin Configuration

Position	Designation
Pin 1	Gate
Pin 2 / Tab	Drain
Pin 3	Source

REVISION HISTORY

Changes from Original (August 2012) to Revision A	Page
• Changed the Transconductance TYP value From: 146 S To: 187 S	2
• Changed $R_{\theta JA}$ From: MAX = 62°C/W To: MAX = 65°C/W	2
• Changed Figure 3	3

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Samples (Requires Login)
CSD18532KCS	ACTIVE	TO-220	KCS	3	50	Pb-Free (RoHS Exempt)	CU SN	N / A for Pkg Type	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

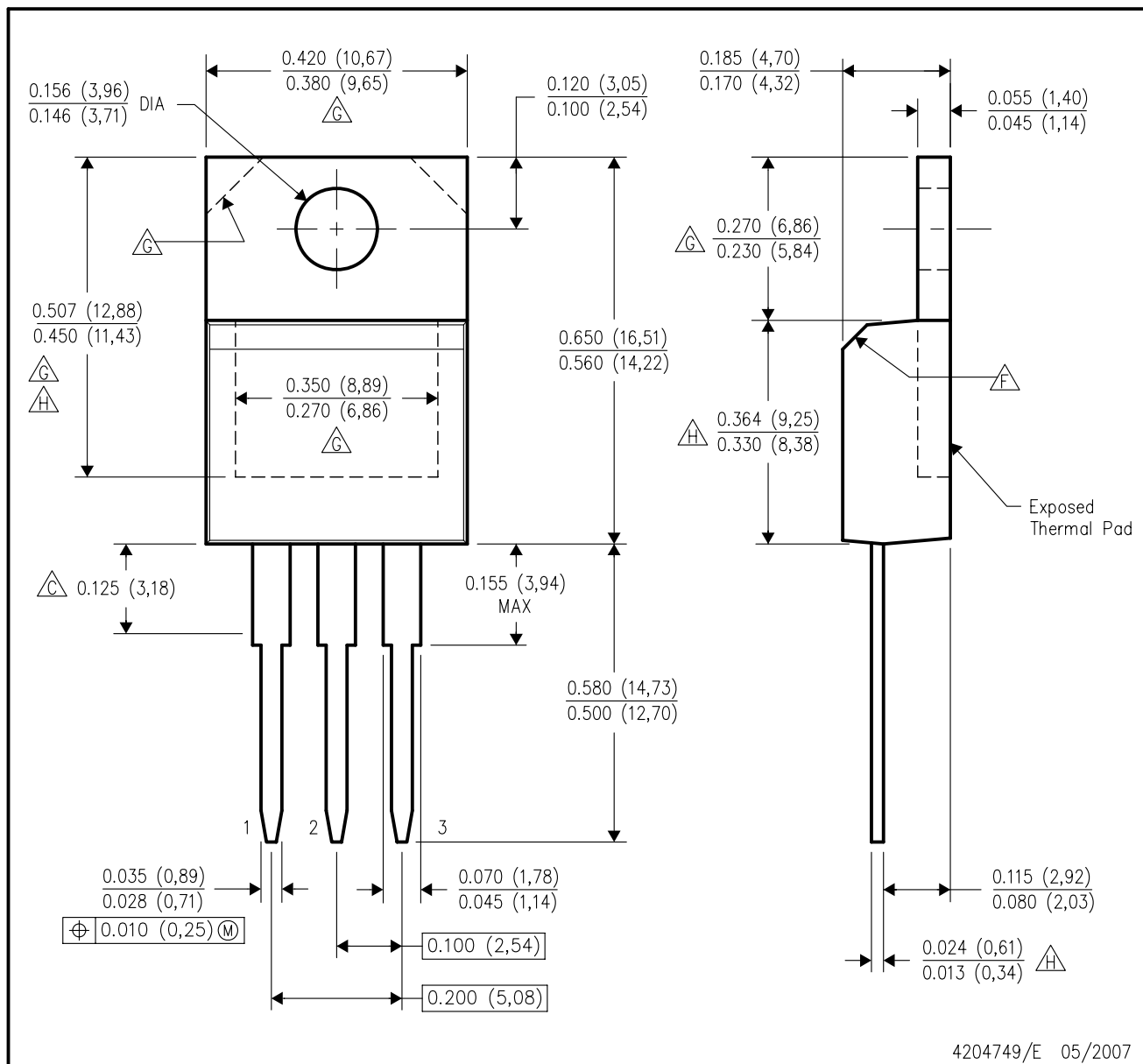
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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KCS (R-PSFM-T3)

PLASTIC FLANGE-MOUNT PACKAGE



4204749/E 05/2007

NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Lead dimensions are not controlled within this area.
- D. All lead dimensions apply before solder dip.
- E. The center lead is in electrical contact with the mounting tab.
- F. The chamfer is optional.
- G. Thermal pad contour optional within these dimensions.
- H. Falls within JEDEC TO-220 variation AB, except minimum lead thickness, minimum exposed pad length, and maximum body length.

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